

SuperMOS – SOT-23-3 30V BV_{DSS}, 19mΩ R_{DS(ON)}, 6.0A I_D N-channel MOSFET

1. Description

The AO3400A is N-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent R_{DS(ON)} with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product AO3400A is Pb-free.

2. Features

- 30V, R_{DS(ON)}=19mΩ(Typ), V_{GS}=10V
R_{DS(ON)}=25mΩ(Typ), V_{GS}=4.5V
- Use trench MOSFET technology
- High density cell design for low R_{DS(on)}
- Material: Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

3. Applications

- PWM applications
- Load switch
- Power management in portable/desktop PCs
- DC/DC conversion

4. Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Size
AO3400A	SOT-23-3L	3400	Halogen free	Tape & Reel	3,000 PCS	UL 94V-0	7 inches

Table-1 Ordering information

5. Pin Configuration and Functions

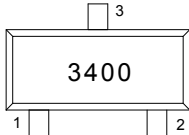
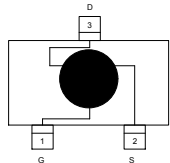
Pin	Function	Outline	Circuit Diagram
1	Gate		
2	Source		
3	Drain		

Table-2 Pin configuration

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	BV_{DSS}	30	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current ^a	$T_A=25^{\circ}C$	6.0	A
	$T_A=70^{\circ}C$	4.6	
Maximum Power Dissipation ^a	$T_A=25^{\circ}C$	1.4	W
	$T_A=70^{\circ}C$	0.9	
Pulsed Drain Current ^c	I_{DM}	30	A
Operating Junction Temperature	T_J	150	°C
Lead Temperature	T_L	260	°C
Storage Temperature Range	T_{stg}	-55 to 150	°C

Thermal resistance ratings

Single Operation					
Parameter		Symbol	Typical	Maximum	Unit
Junction-to-Ambient Thermal Resistance ^a	$t \leq 10$ s	$R_{\theta JA}$	75	90	°C/W
Junction-to-Case Thermal Resistance	Steady State	$R_{\theta JC}$	43	70	

Note:

- a Surface mounted on FR4 Board using 1 square inch pad size, 1oz copper
- b Surface mounted on FR4 board using minimum pad size, 1oz copper
- c Repetitive rating, pulse width limited by junction temperature, $t_p=10\mu s$, Duty Cycle=1%

Electrical Characteristics

At TA = 25°C unless otherwise specified

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	30			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=24V, V_{GS}=0V$			1	μA
Gate-to-source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 12V$			± 100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS}=V_{DS}, I_D=250\mu A$	0.6	1.0	1.3	V
Drain-to-source On-resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=6.0A$		19.0	28.0	m Ω
		$V_{GS}=4.5V, I_D=5.0A$		25.0	33.0	
		$V_{GS}=2.5V, I_D=3.0A$		33.0	51.0	
Forward Trans conductance	g_{FS}	$V_{DS}=5.0V, I_D=5.8A$		7.8	15	S
CHARGES, CAPACITANCES AND GATE RESISTANCE						
Input Capacitance	C_{ISS}	$V_{GS}=0V, f=1MHz, V_{DS}=10V$		550		pF
Output Capacitance	C_{OSS}			62		
Reverse Transfer Capacitance	C_{RSS}			48		
Total Gate Charge	$Q_{G(TOT)}$	$V_{GS}=4.5V, V_{DS}=10V, I_D=5.8A$		6.7		nC
Threshold Gate Charge	$Q_{G(TH)}$			0.75		
Gate-to-Source Charge	Q_{GS}			1.65		
Gate-to-Drain Charge	Q_{GD}			1.78		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	$t_{d(ON)}$	$V_{GS}=4.5V, V_{DS}=10V, R_L=10\Omega, R_G=6\Omega$		3.8		ns
Rise Time	t_r			13.0		
Turn-Off Delay Time	$t_{d(OFF)}$			14.2		
Fall Time	t_f			2.0		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=1.0A$		0.75	1.5	V

7. Typical Characteristic

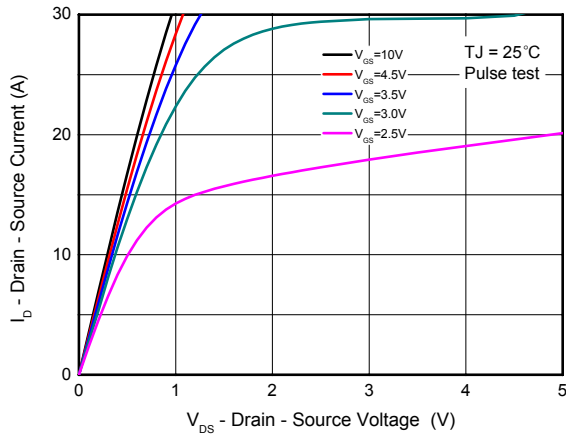


Figure 1. Typ. Output

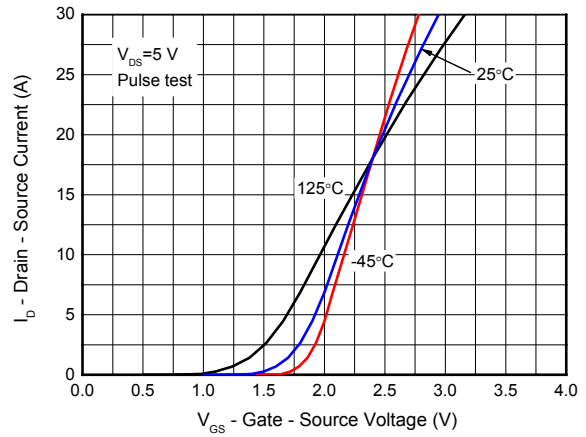


Figure 2. Transfer Characteristics

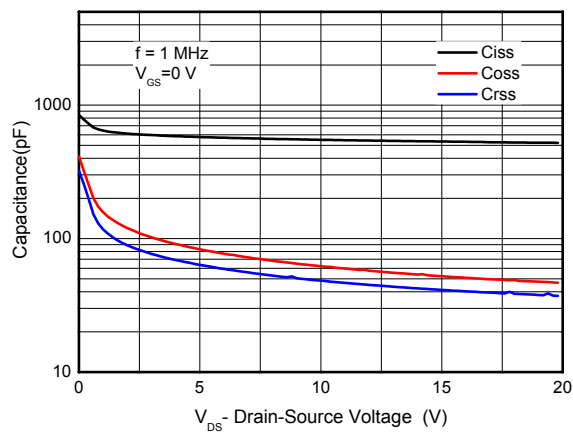


Figure 3. Capacitance Characteristics

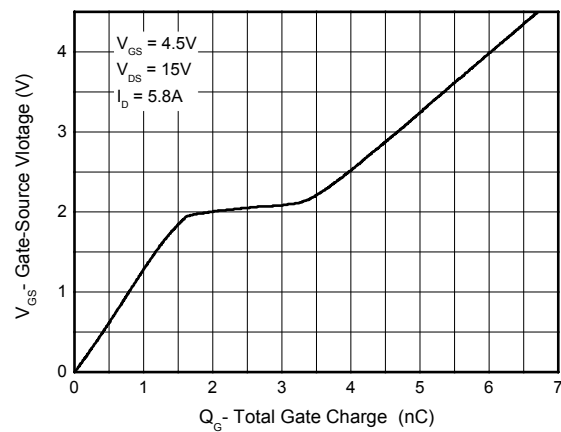


Figure 4. Gate Charge Waveform

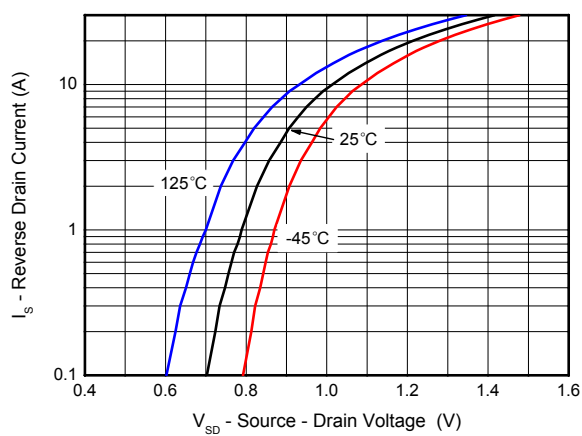


Figure 5. Body-Diode Characteristics

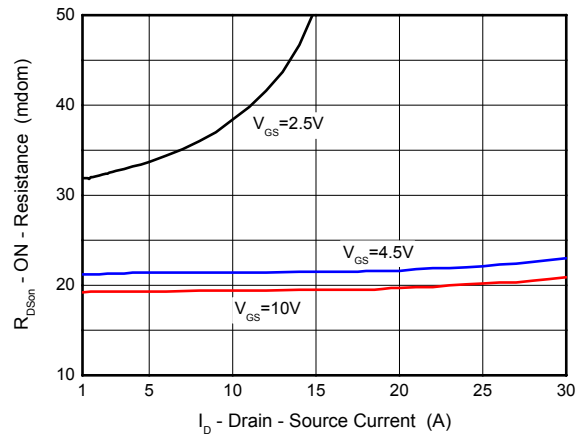


Figure 6. $R_{ds(on)}$ -Drain Current

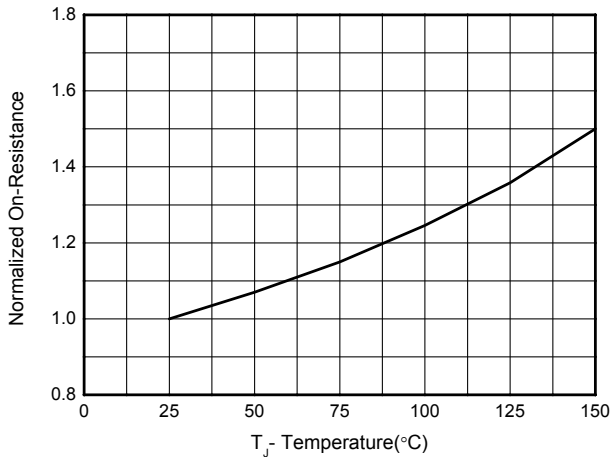


Figure 7. Rdson-Junction Temperature(°C)

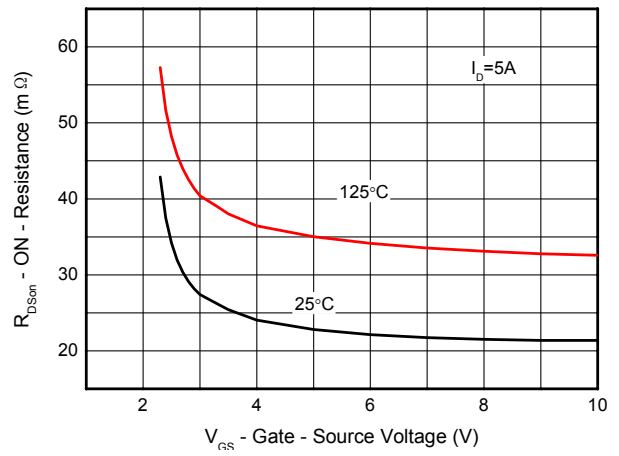


Figure 8: On-Resistance vs. Gate-Source

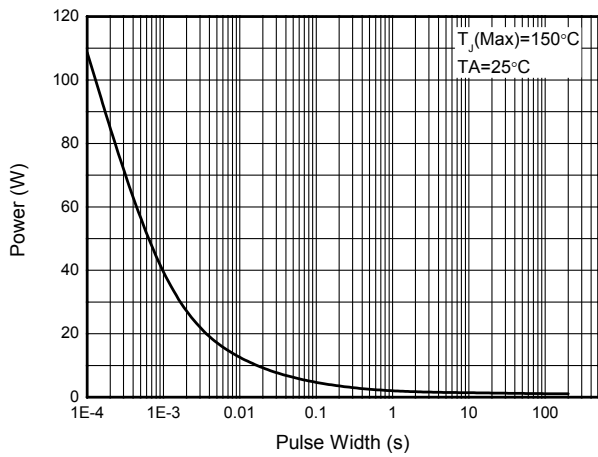


Figure 9: Single Pulse Power Rating Junction-to-Ambient (Note E)

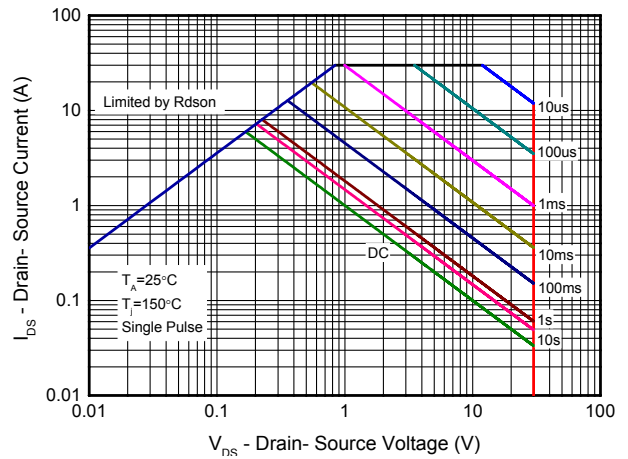
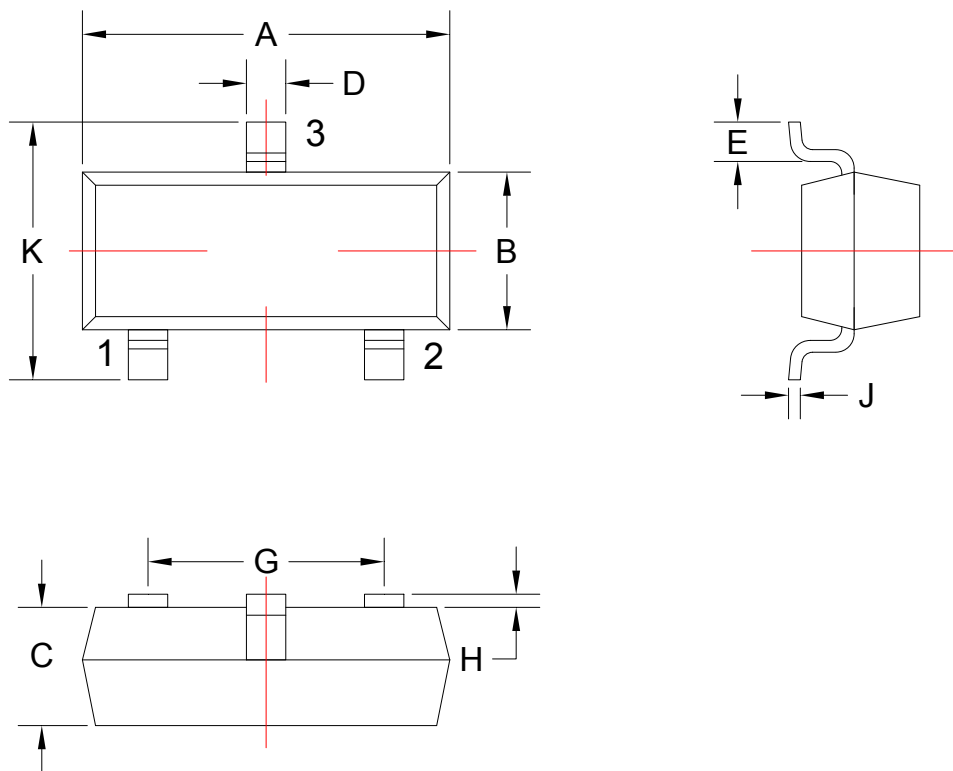


Figure 10. Maximum Safe Operation Area

8. Dimension and Patterns (SOT-23-3)



COMMON DIMENSIONS				
SYMBOL	MILLIMETERS		INCHS	
	MIN	MAX	MIN	MAX
A	2.8	3	0.11	0.118
B	1.5	1.7	0.059	0.067
C	1	1.2	0.039	0.047
D	0.3	0.5	0.012	0.02
E	0.25	0.55	0.01	0.022
G	1.90 TYP.		0.075 TYP.	
H	0	0.1	0	0.004
J	0.04	0.21	0.002	0.008
K	2.6	3	0.102	0.118

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